

PRECISION 4.1 VOLT MICROPOWER VOLTAGE REFERENCE

ZR4040-4.1

ISSUE 3 - FEBRUARY 1998

DEVICE DESCRIPTION

The ZR4040-4.1 uses a bandgap circuit design to achieve a precision micropower voltage reference of 4.1 volts. The device is available in small outline surface mount packages, ideal for applications where space saving is important, as well as packages for through hole requirements.

The ZR4040-4.1 design provides a stable voltage without an external capacitor and is stable with capacitive loads. The ZR4040-4.1 is recommended for operation between $60\mu\text{A}$ and 15mA and so is ideally suited to low power and battery powered applications.

Excellent performance is maintained to an absolute maximum of 25mA , however the rugged design and 20 volt processing allows the reference to withstand transient effects and currents up to 200mA . Superior switching capability allows the device to reach stable operating conditions in only a few microseconds.

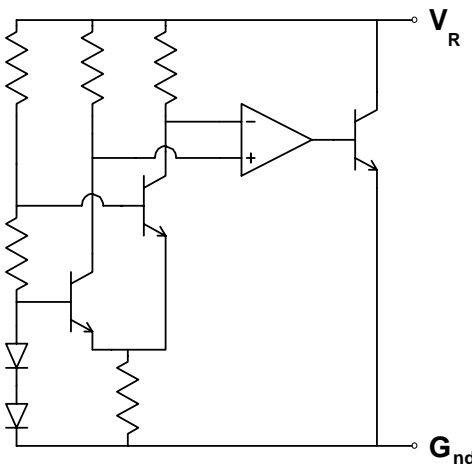
FEATURES

- Small outline SO8 and SOT23 packages
- TO92 style package
- No stabilising capacitor required
- Typical T_c $20\text{ppm}/^\circ\text{C}$
- Typical slope resistance 0.55Ω
- 2% and 1% tolerance
- Industrial temperature range
- Operating current $60\mu\text{A}$ to 15mA

APPLICATIONS

- Battery powered and portable equipment.
- Metering and measurement systems.
- Instrumentation.
- Test equipment.
- Data acquisition systems.
- Precision power supplies.
- Crystal oscillators.

SCHEMATIC DIAGRAM



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ABSOLUTE MAXIMUM RATING

Reverse Current	25mA
Forward Current	25mA
Operating Temperature	-40 to 85°C
Storage Temperature	-55 to 125°C

Power Dissipation (T_{amb}=25°C)

SOT23	330mW
SO8	625mW
E-Line, 3 pin (TO92)	500mW

ELECTRICAL CHARACTERISTICS

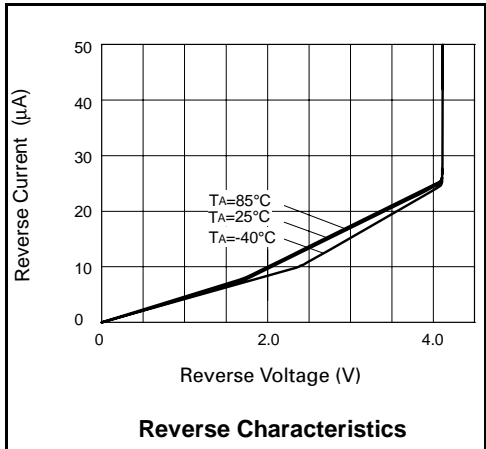
TEST CONDITIONS (Unless otherwise stated) T_{amb}= 25°C

SYMBOL	PARAMETER	CONDITION	LIMITS			TOL	UNITS
			MIN	TYP	MAX		
V _R	Reverse Breakdown Voltage	I _R =150μA	4.05 4.01	4.096 4.096	4.14 4.18	1 2	V
I _{MIN}	Minimum Operating Current			25	60		μA
I _R	Recommended Operating Current		0.06		15		mA
T _C †	Average Reverse Breakdown Voltage Temp. Co.	I _{R(min)} to I _{R(max)}		20	100		ppm/°C
R _S §	Slope Resistance			0.55	2		Ω
Z _R	Reverse Dynamic Impedance	I _R = 1mA f = 100Hz I _{AC} = 0.1 I _R		0.5	1.2		Ω
E _N	Wideband Noise Voltage	I _R = 1mA f = 10Hz to 10kHz		90			μV(rms)

$$\dagger T_C = \frac{(V_{R(max)} - V_{R(min)}) \times 1000000}{V_R \times (T_{(max)} - T_{(min)})}$$

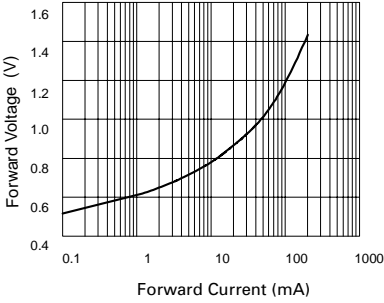
Note: V_{R(max)} - V_{R(min)} is the maximum deviation in reference voltage measured over the full operating temperature range.

$$\S R_S = \frac{V_R \text{ Change}(I_R(\min) \text{ to } I_R(\max))}{I_R(\max) - I_R(\min)}$$

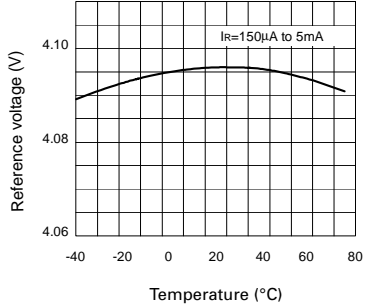


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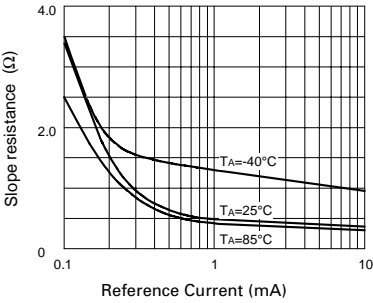
TYPICAL CHARACTERISTICS



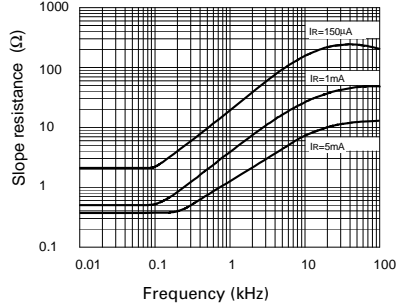
Forward Characteristics



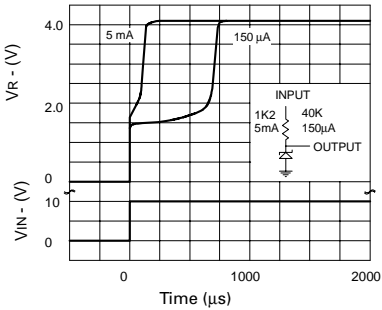
Temperature Drift



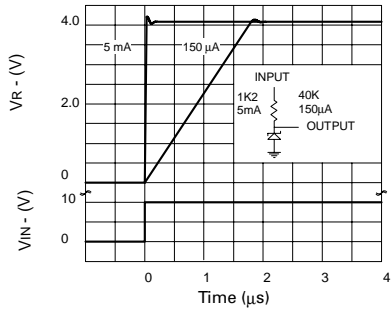
Slope Resistance v Current



Slope Resistance v Frequency



Transient Response (Single Pulse)

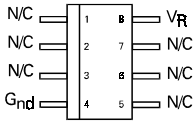


Transient Response (Repetitive Pulse)

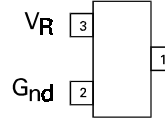
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CONNECTION DIAGRAMS

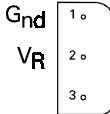
SO8 Package Suffix - N8



SOT23 Package Suffix - F



E-Line, 3 pin, Rev Package Suffix - R



ORDERING INFORMATION

Part Number	Tol%	Package	Partmark
ZR40402F41	2	SOT23	40E
ZR40401F41	1	SOT23	40F
ZR40402N841	2	SO8	ZR4040241
ZR40401N841	1	SO8	ZR4040141
ZR40402R41	2	E-Line *	ZR4040241
ZR40401R41	1	E-Line *	ZR4040141

* E-Line, 3 pin Reversed